Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	(((semiconductor or dielectric) adj4 (wafer or substrate)) and (ionizer or detect\$3) near3 (multi adj2 layer) and ion adj trap).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 18:19
SI	603479	(semiconductor or dielectric or insulating) near4 (wafer or substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 16:08
S2	10583	S1 and (multi-layer or stack) near3 (wafer or substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 10:57
S3	27	S1 and ioniser	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 10:57
S4	100	S1 and ion adj trap	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 13:20
S5	0	S3 and S4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 11:21
S6	2	"4926056".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 11:22
S7	1439	S1 and mass adj spectrometer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 12:00
S8	9	S1 near4 mass adj spectrometer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ОИ	2005/06/30 12:00
S10	48	miniature adj mass adj spectrometer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 16:06
S11	40951	(pai pau taylor).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 16:07

S12	1025	S11 and (semiconductor or dielectric or insulating) near4 (wafer or substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 16:08
S13	2	S12 and ionizer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 16:10
S14	6	S12 and mass adj3 (spectrometer or analyzer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 16:14
S15	2	S12 and ion adj trap	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 16:14